

ERRATA

**Erratum: Optical phonons in quantum-wire structures
[JETP Lett. 67, No. 2, 120–134 (25 January 1998)]**

A. Milekhin, Yu. Pusep, Yu. Yanovskiĭ, V. Preobrazhenskiĭ,
and B. Semyagin

Institute of Semiconductor Physics, 630090 Novosibirsk, Russia
Pis'ma Zh. Eksp. Teor. Fiz. **67**, No. 8, 597 (25 April 1998)

[S0021-3640(98)01508-4]

PACS numbers: 63.22.+m, 78.30.Fs, 99.10.+g

The first two sentences of the body of the paper should read as follows:

Progress in molecular-beam epitaxy (MBE) technology has made it possible to grow perfect GaAs/AlAs superlattices (SLs) on high-index GaAs surfaces, such as (011),¹ (112),^{2,3} and (311).²⁻⁴ The lower symmetry of these SLs as compared with SLs on (100)-oriented GaAs/AlAs leads to optical anisotropy in the plane of the SL layers.²⁻⁶

Also, Eq. (1) should read

$$q_m = m\pi/\{(n + \delta)d\}, \quad d = a/\sqrt{11}. \quad (1)$$